

NCP361

USB Positive Overvoltage Protection Controller with Internal PMOS FET and Overcurrent Protection

NCP361 is able to disconnect the systems from its output pin in case wrong VBUS operating conditions is detected. The system is positive over-voltage protected up to +20 V.

Thanks to this device using internal PMOS FET, no external device is necessary, reducing the system cost and the PCB area of the application board.

NCP361 is able to instantaneously disconnect the output from the input if the input voltage exceeds the overvoltage threshold (5.675 V). Thanks to an overcurrent protection, the integrated PMOS is turning off when the charge current exceeds current limit (see options in ordering information).

NCP361 provides a negative going flag ($\overline{\text{FLAG}}$) output, which alerts the system that voltage, current or overtemperature faults have occurred.

In addition, the device has ESD-protected input (15 kV Air) when bypassed with a 1 μF or larger capacitor.

Features

- Overvoltage Protection up to 20 V
- On-chip PMOS Transistor
- Overvoltage Lockout (OVLO)
- Undervoltage Lockout (UVLO)
- Overcurrent Protection
- Alert $\overline{\text{FLAG}}$ Output
- $\overline{\text{EN}}$ Enable Pin
- Thermal Shutdown
- Compliance to IEC61000-4-2 (Level 4)
 - 8 kV (Contact)
 - 15 kV (Air)
- ESD Ratings: Machine Model = B
Human Body Model = 2
- 6 Leads UDFN 2x2 mm Package
- 5 Leads TSOP-5 3x3 mm Package
- This is a Pb-Free Device

Applications

- USB Devices
- Mobile Phones
- Peripheral
- Personal Digital Applications
- MP3 Players
- Set Top Boxes



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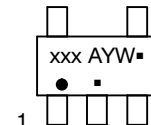


6 PIN UDFN
CASE 517AB



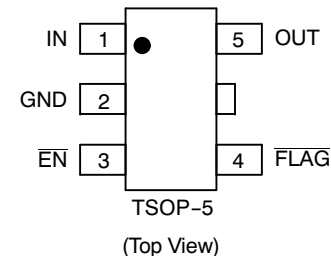
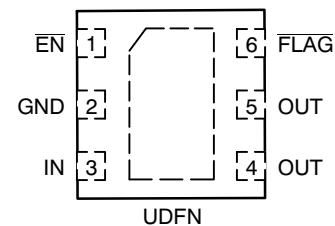
TSOP-5
CASE 483

MARKING DIAGRAMS



xxx = Specific Device Code
 M = Date Code
 A = Assembly Location
 Y = Year
 W = Work Week
 ■ = Pb-Free Package
 (Note: Microdot may be in either location)

PIN CONNECTIONS



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 9 of this data sheet.

NCP361

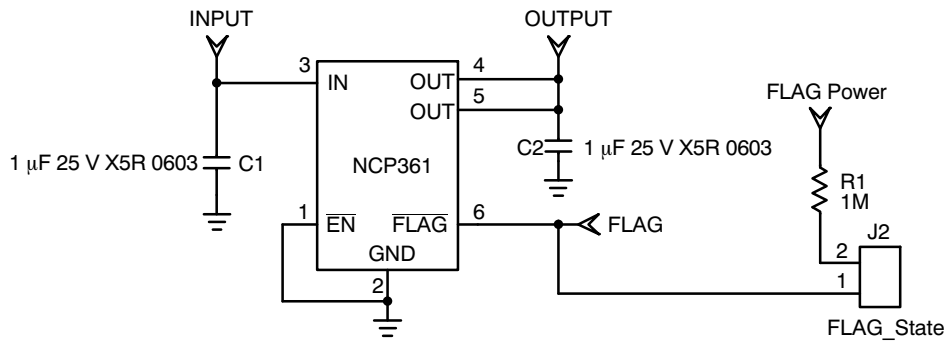


Figure 1. Typical Application Circuit (UDFN Pinout)

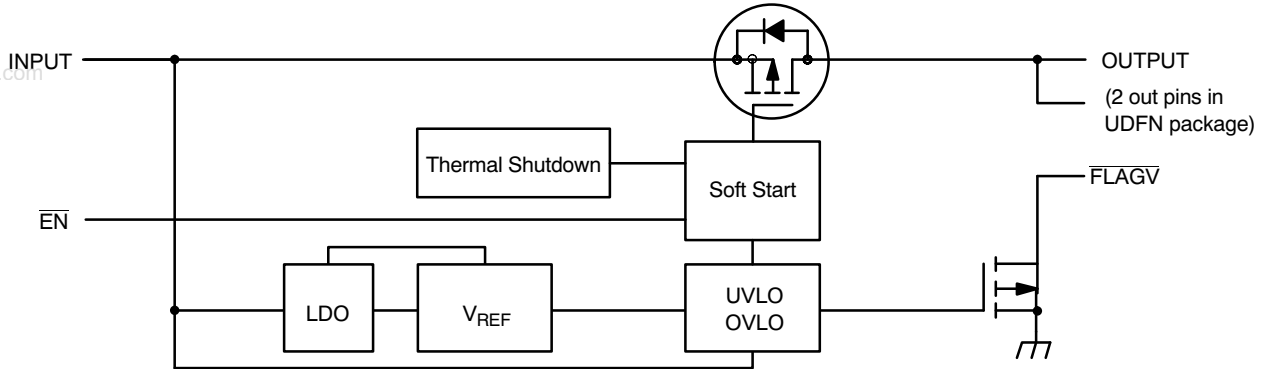


Figure 2. Functional Block Diagram

PIN FUNCTION DESCRIPTION (UDFN Package)

Pin No.	Name	Type	Description
1	$\overline{\text{EN}}$	INPUT	Enable Pin. The device enters in shutdown mode when this pin is tied to a high level. In this case the output is disconnected from the input. To allow normal functionality, the $\overline{\text{EN}}$ pin shall be connected to GND to a pull down or to a I/O pin. This pin does not have an impact on the fault detection.
2	GND	POWER	Ground
3	IN	POWER	Input Voltage Pin. This pin is connected to the VBUS. A 1 μF low ESR ceramic capacitor, or larger, must be connected between this pin and GND.
4, 5	OUT	OUTPUT	Output Voltage Pin. The output is disconnected from the VBUS power supply when the input voltage is above OVLO threshold or below UVLO threshold. A 1 μF capacitor must be connected to these pins. The two OUT pins must be hardwired to common supply.
6	$\overline{\text{FLAG}}$	OUTPUT	Fault Indication Pin. This pin allows an external system to detect a fault on VBUS pin. The $\overline{\text{FLAG}}$ pin goes low when input voltage exceeds OVLO threshold. Since the $\overline{\text{FLAG}}$ pin is open drain functionality, an external pull up resistor to V_{CC} must be added.

PIN FUNCTION DESCRIPTION (TSOP-5 Package)

Pin No.	Name	Type	Description
1	IN	POWER	Input Voltage Pin. This pin is connected to the VBUS. A 1 μF low ESR ceramic capacitor, or larger, must be connected between this pin and GND.
2	GND	POWER	Ground
3	$\overline{\text{EN}}$	INPUT	Enable Pin. The device enters in shutdown mode when this pin is tied to a high level. In this case the output is disconnected from the input. To allow normal functionality, the $\overline{\text{EN}}$ pin shall be connected to GND to a pull down or to a I/O pin. This pin does not have an impact on the fault detection.
4	$\overline{\text{FLAG}}$	OUTPUT	Fault Indication Pin. This pin allows an external system to detect a fault on VBUS pin. The $\overline{\text{FLAG}}$ pin goes low when input voltage exceeds OVLO threshold. Since the $\overline{\text{FLAG}}$ pin is open drain functionality, an external pull up resistor to V_{CC} must be added.
5	OUT	OUTPUT	Output Voltage Pin. The output is disconnected from the VBUS power supply when the input voltage is above OVLO threshold or below UVLO threshold. A 1 μF capacitor must be connected to this pin.

NOTE: Pin out provided for concept purpose only and might change in the final product

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MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Minimum Voltage (IN to GND)	$V_{min_{IN}}$	-0.3	V
Minimum Voltage (All others to GND)	V_{min}	-0.3	V
Maximum Voltage (IN to GND)	$V_{max_{IN}}$	21	V
Maximum Voltage (All others to GND)	V_{max}	7.0	V
Maximum DC Current from V_{in} to V_{out} (PMOS)	I_{max}	600	mA
Thermal Resistance, Junction-to-Air	$R_{\theta JA}$	240	$^{\circ}C/W$
Operating Ambient Temperature Range	T_A	-40 to +85	$^{\circ}C$
Storage Temperature Range	T_{stg}	-65 to +150	$^{\circ}C$
Junction Operating Temperature	T_J	150	$^{\circ}C$
ESD Withstand Voltage (IEC 61000-4-2) Human Body Model (HBM), Model = 2 (Note 1) Machine Model (MM) Model = B (Note 2)	V_{esd}	15 Air, 8.0 Contact 2000 200	kV V V
Moisture Sensitivity	MSL	Level 1	-

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- Human Body Model, 100 pF discharged through a 1.5 k Ω resistor following specification JESD22/A114.
- Machine Model, 200 pF discharged through all pins following specification JESD22/A115.

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ELECTRICAL CHARACTERISTICS

(Min/Max limits values ($-40^{\circ}\text{C} < T_A < +85^{\circ}\text{C}$) and $V_{in} = +5.0\text{ V}$. Typical values are $T_A = +25^{\circ}\text{C}$, unless otherwise noted.)

Characteristic	Symbol	Conditions	Min	Typ	Max	Unit
Input Voltage Range	V_{in}		1.2		20	V
Undervoltage Lockout Threshold	UVLO	V_{in} falls down UVLO threshold	2.85	3.0	3.15	V
Overvoltage Lockout Hysteresis	UVLO _{hyst}		50	70	90	mV
Overvoltage Lockout Threshold	OVLO	V_{in} rises up OVLO threshold	5.43	5.675	5.9	V
Overvoltage Lockout Hysteresis	OVLO _{hyst}		50	100	125	mV
V_{in} versus V_{out} Dropout	V_{drop}	$V_{in} = 5\text{ V}$, I charge = 500 mA		150	200	mV
Overcurrent Limit	I_{lim}	$V_{in} = 5\text{ V}$	550	750	950	mA
Supply Quiescent Current	I_{dd}	No Load, $V_{in} = 5.25\text{ V}$		20	35	μA
Standby Current	I_{std}	$V_{in} = 5\text{ V}$, EN = 1.2 V		26	37	μA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 20\text{ V}$, $V_{GS} = 0\text{ V}$		0.08		μA
FLAG Output Low Voltage	V_{olflag}	$V_{in} > \text{OVLO}$ Sink 1 mA on FLAG pin			400	mV
FLAG Leakage Current	FLAG _{leak}	FLAG level = 5 V		5.0		nA
$\overline{\text{EN}}$ Voltage High	V_{ih}	V_{in} from 3.3 V to 5.25 V	1.2			V
$\overline{\text{EN}}$ Voltage Low	V_{ol}	V_{in} from 3.3 V to 5.25 V			0.4	V
EN Leakage Current	EN _{leak}	EN = 5.5 V or GND		170		nA

TIMINGS

Start Up Delay	t_{on}	From $V_{in} > \text{UVLO}$ to $V_{out} = 0.8 \times V_{in}$, See Fig 14		4.0	15	ms
FLAG going up Delay	t_{start}	From $V_{in} > \text{UVLO}$ to FLAG = 1.2 V, See Fig 14		3.0		ms
Output Turn Off Time	t_{off}	From $V_{in} > \text{OVLO}$ to $V_{out} \leq 0.3\text{ V}$, See Fig 15 V_{in} increasing from 5 V to 8 V at 3 V/ μs . No output capacitor.		0.7	1.5	μs
Alert Delay	t_{stop}	From $V_{in} > \text{OVLO}$ to FLAG $\leq 0.4\text{ V}$, See Fig 15 V_{in} increasing from 5 V to 8 V at 3 V/ μs		1.0		μs
Disable Time	t_{dis}	From $\overline{\text{EN}} 0.4$ to 1.2V to $V_{out} \leq 0.3\text{ V}$, See Fig 16 $V_{in} = 4.75\text{ V}$. No output capacitor.		3.0		μs
Thermal Shutdown Temperature	T_{sd}			150		$^{\circ}\text{C}$
Thermal Shutdown Hysteresis	T_{sdhyst}			30		$^{\circ}\text{C}$

TYPICAL OPERATING CHARACTERISTICS

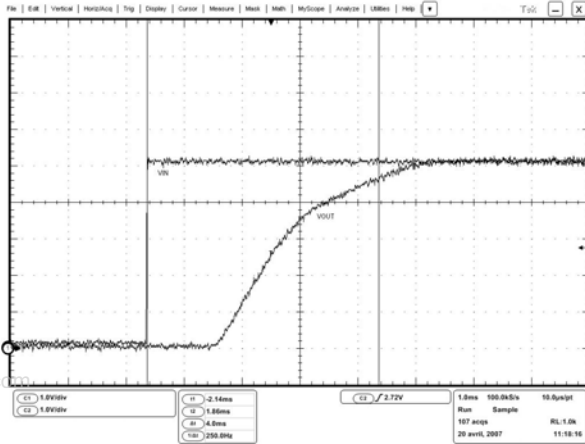


Figure 3. Start Up. Vin=Ch1, Vout=Ch2

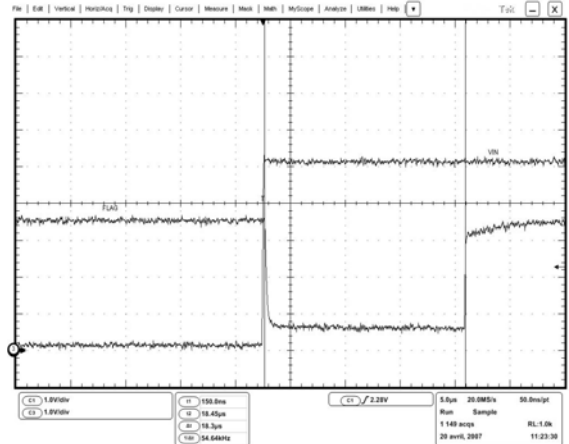


Figure 4. FLAG Going Up Delay. Vin=Ch1, FLAG=Ch3

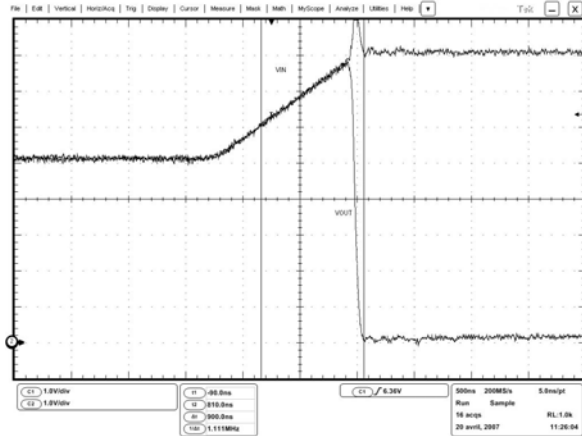


Figure 5. Output Turn Off time. Vin=Ch1, Vout=Ch2

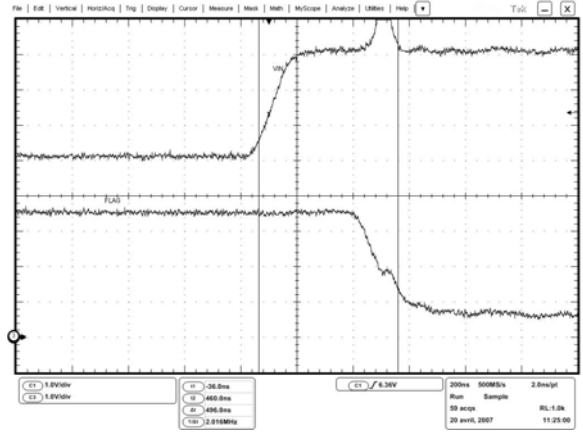


Figure 6. Alert Delay. Vout=Ch1, FLAG=Ch3

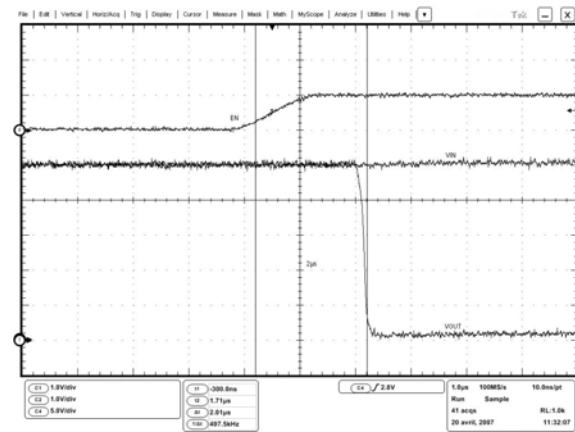


Figure 7. Disable Time. EN=Ch4, Vin=Ch1, Vout=Ch2

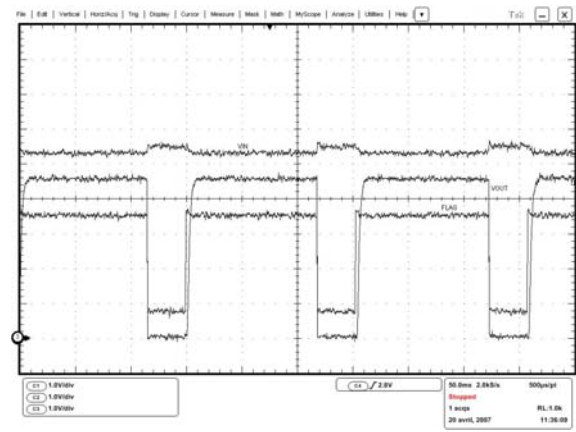


Figure 8. Thermal Shutdown. Vin=Ch1, Vout=Ch2, FLAG=Ch3

NCP361

TYPICAL OPERATING CHARACTERISTICS

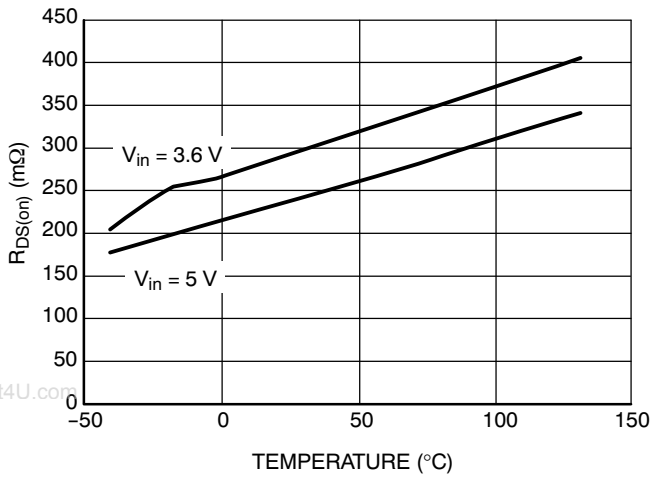


Figure 9. R_{DS(on)} vs. Temperature (Load = 500 mA)

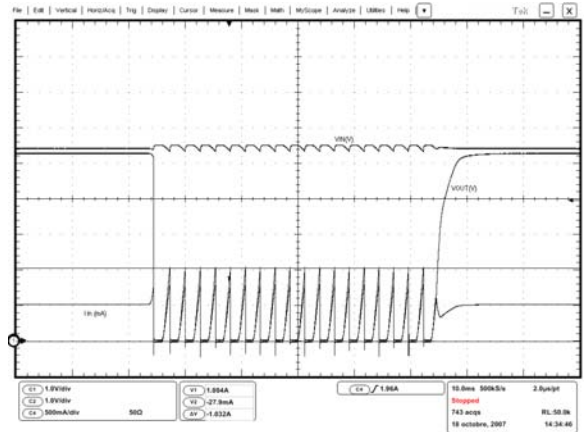


Figure 10. Output Short Circuit

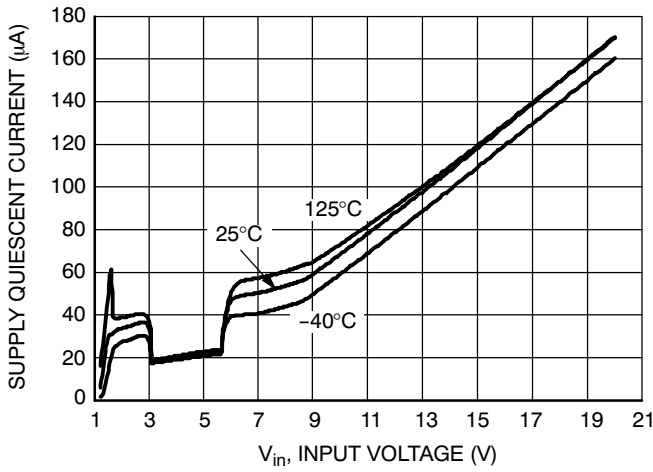


Figure 11. Quiescent Current vs. Input Voltage

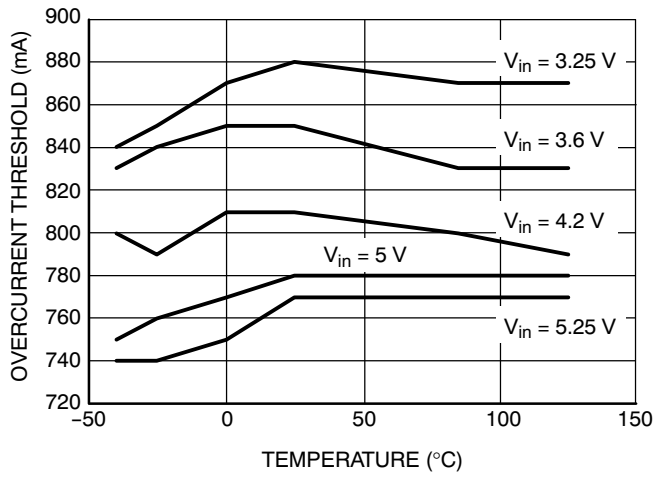


Figure 12. Overcurrent Protection Threshold vs. Temperature

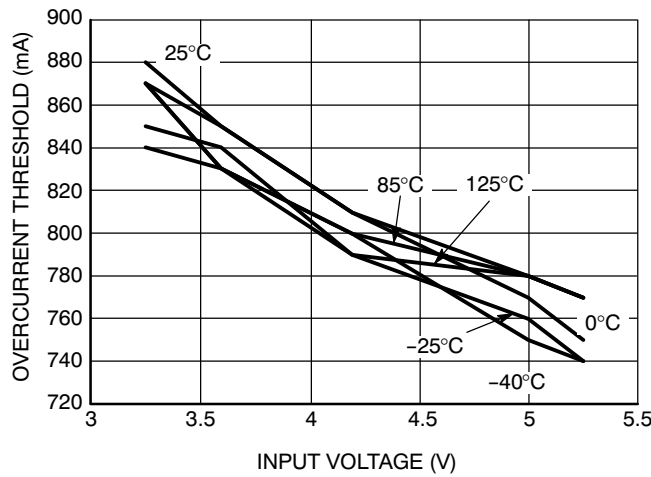


Figure 13. Overcurrent Protection Threshold vs. Input Voltage

NCP361

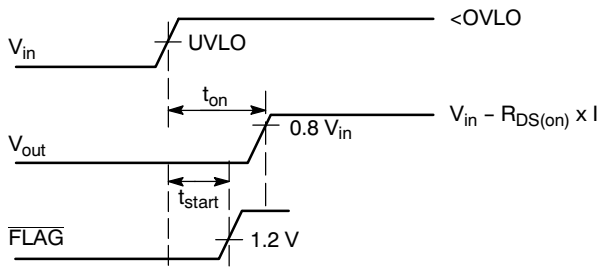


Figure 14. Start Up Sequence

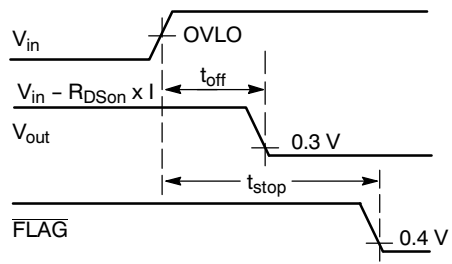


Figure 15. Shutdown on Over Voltage Detection

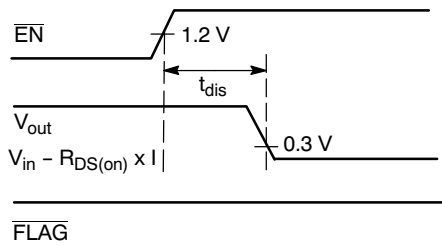


Figure 16. Disable on $\overline{EN} = 1$

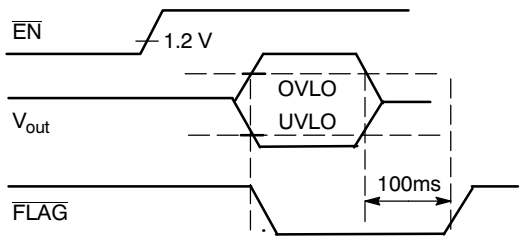


Figure 17. \overline{FLAG} Response with $\overline{EN} = 1$

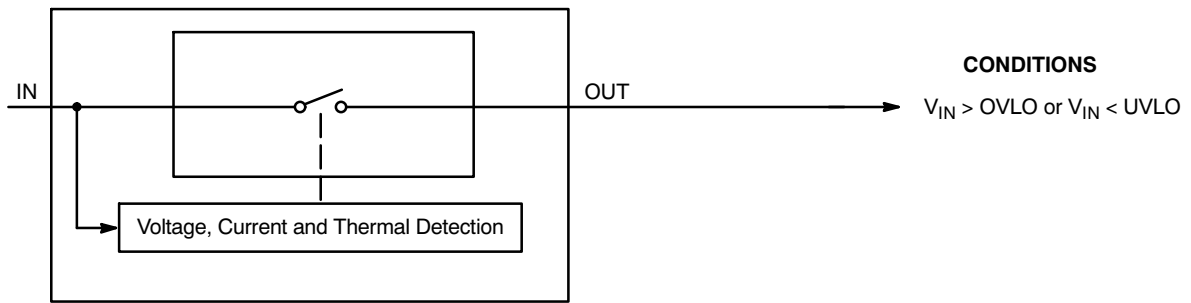


Figure 18.

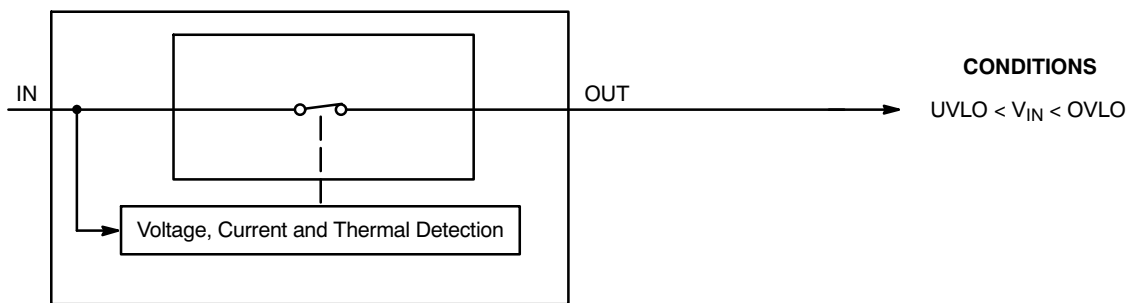


Figure 19.

Operation

NCP361 provides overvoltage protection for positive voltage, up to 20 V. A PMOS FET protects the systems (i.e.: VBUS) connected on the V_{out} pin, against positive overvoltage. The Output follows the VBUS level until OVLO threshold is overtaken.

Undervoltage Lockout (UVLO)

To ensure proper operation under any conditions, the device has a built-in undervoltage lock out (UVLO) circuit. During V_{in} positive going slope, the output remains disconnected from input until V_{in} voltage is above 3.0 V nominal. The \overline{FLAGV} output is pulled to low as long as V_{in} does not reach UVLO threshold. This circuit has a 70 mV hysteresis to provide noise immunity to transient condition.

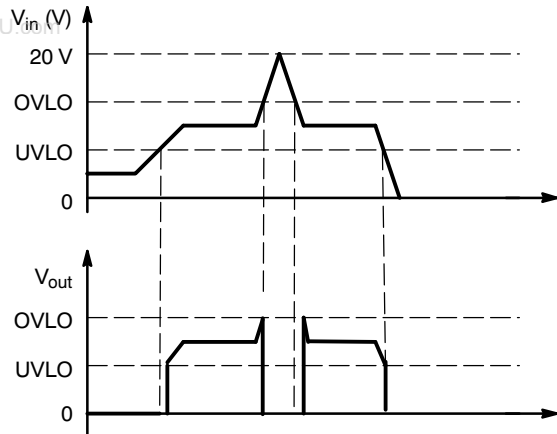


Figure 20. Output Characteristic vs. V_{in}

Overvoltage Lockout (OVLO)

To protect connected systems on V_{out} pin from overvoltage, the device has a built-in overvoltage lock out (OVLO) circuit. During overvoltage condition, the output remains disabled until the input voltage exceeds 6.0 V.

\overline{FLAG} output is tied to low until V_{in} is higher than OVLO. This circuit has a 100 mV hysteresis to provide noise immunity to transient conditions.

Overcurrent Protection (OCP)

The NCP361 integrates overcurrent protection to prevent system/battery overload or defect. The current limit threshold is internally set at 750 mA. This value can be changed from 150 mA to 750 mA by a metal tweak, please contact your ON Semiconductor representative for availability. During current fault, the internal PMOS FET is automatically turned off (1 μ s) if the charge current exceeds I_{lim} . NCP361 goes into turn on and turn off mode as long as defect is present. The internal t_{on} delay (4 ms typical) allows limiting thermal dissipation. The Flag pin goes to low level when an overcurrent fault appears. That allows the microcontroller to count defect events and turns off the PMOS with EN pin.

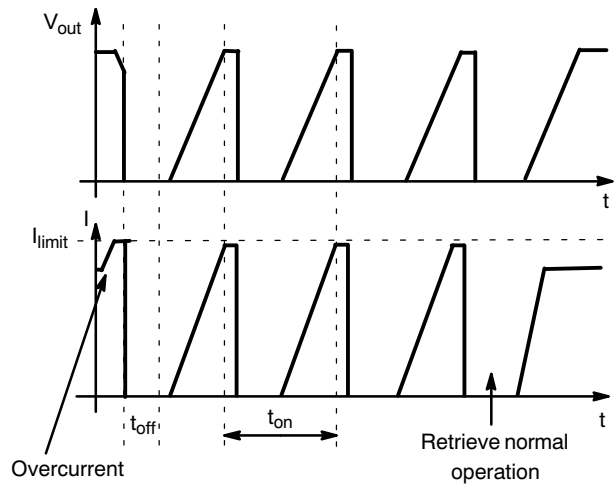


Figure 21. Overcurrent Event Example

\overline{FLAG} Output

NCP361 provides a \overline{FLAG} output, which alerts external systems that a fault has occurred.

This pin is tied to low as soon as: $1.2\text{ V} < V_{in} < UVLO$, $V_{in} > OVLO$, $I_{charge} > I_{limit}$, $T_J > 150^\circ\text{C}$. When NCP361 recovers normal condition, \overline{FLAG} is held high. The pin is an open drain output, thus a pull up resistor (typically 1 M Ω - Minimum 10 k Ω) must be provided to V_{CC} . \overline{FLAG} pin is an open drain output.

\overline{EN} Input

To enable normal operation, the \overline{EN} pin shall be forced to low or connected to ground. A high level on the pin disconnects OUT pin from IN pin. \overline{EN} does not overdrive an OVLO or UVLO fault.

Internal PMOS FET

The NCP361 includes an internal PMOS FET to protect the systems, connected on OUT pin, from positive overvoltage. Regarding electrical characteristics, the $R_{DS(on)}$, during normal operation, will create low losses on V_{out} pin, characterized by V_{in} versus V_{out} dropout.

ESD Tests

The NCP361 fully supports the IEC61000-4-2, level 4 (Input pin, 1 μ F mounted on board). That means, in Air condition, V_{in} has a $\pm 15\text{ kV}$ ESD protected input. In Contact condition, V_{in} has $\pm 8\text{ kV}$ ESD protected input. Please refer to Figure 22 to see the IEC61000-4-2 electrostatic discharge waveform.

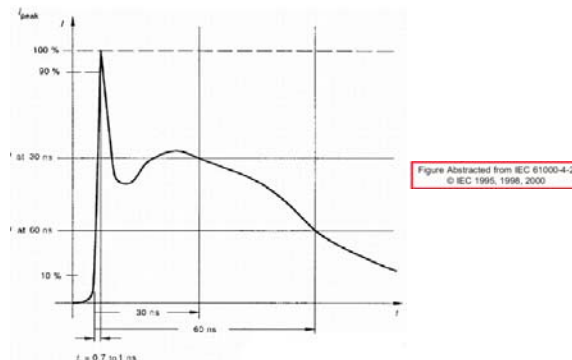


Figure 22.

NCP361

ORDERING INFORMATION

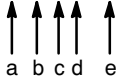
Device	Marking	Package	Shipping†
NCP361xMUxxTBG	AD	UDFN6 (Pb-Free)	3000 / Tape & Reel
NCP361xSNxxT1G	XXX	TSOP-5 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

SELECTION GUIDE

The NCP361 can be available in several undervoltage and overvoltage thresholds versions. Part number is designated as follows:

NCP361xxxxTxG



www.DataSheet4U.com

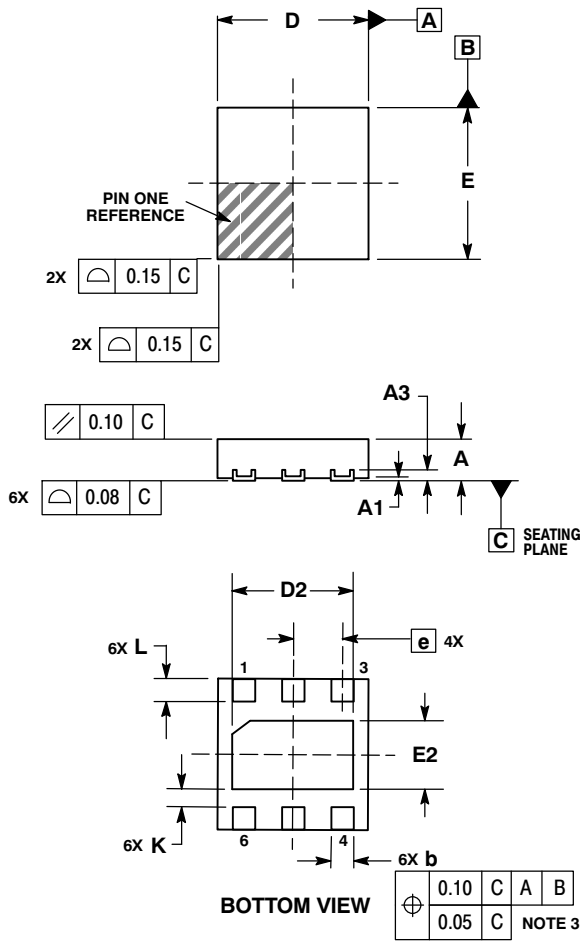
Code	Contents
a	Overcurrent Threshold -: 750 mA
b	Package MU: UDFN SN: TSOP-5
c	UVLO Typical Threshold -: 3.00 V
d	OVLO Typical Threshold -: 5.675 V
e	Tape & Reel Type B: = 3000 1: = 3000

NOTE: Additional current limit, UVLO and OVLO can be available.
Please contact your ON Semiconductor representative for availability.

NCP361

PACKAGE DIMENSIONS

UDFN6 2x2, 0.65P
CASE 517AB-01
ISSUE O



NOTES:

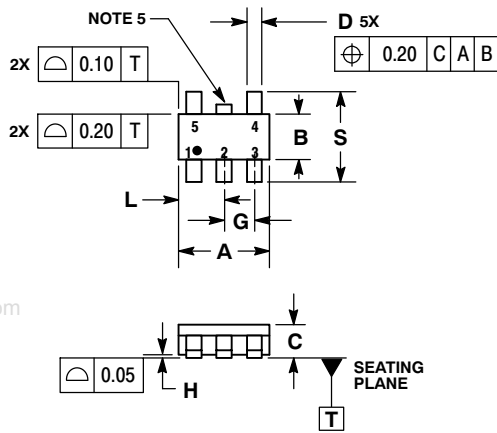
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.20mm FROM TERMINAL.
4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

DIM	MILLIMETERS	
	MIN	MAX
A	0.45	0.55
A1	0.00	0.05
A3	0.127 REF	
b	0.25	0.35
D	2.00 BSC	
D2	1.50	1.70
E	2.00 BSC	
E2	0.80	1.00
e	0.65 BSC	
K	0.20	---
L	0.25	0.35

NCP361

PACKAGE DIMENSIONS

TSOP-5 CASE 483-02 ISSUE F

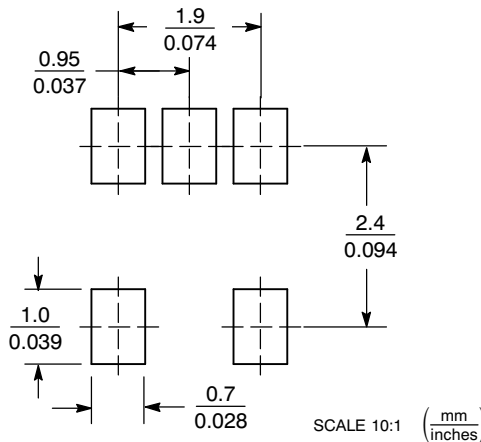


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.
5. OPTIONAL CONSTRUCTION: AN ADDITIONAL TRIMMED LEAD IS ALLOWED IN THIS LOCATION. TRIMMED LEAD NOT TO EXTEND MORE THAN 0.2 FROM BODY.

MILLIMETERS		
DIM	MIN	MAX
A	3.00	BSC
B	1.50	BSC
C	0.90	1.10
D	0.25	0.50
G	0.95	BSC
H	0.01	0.10
J	0.10	0.26
K	0.20	0.60
L	1.25	1.55
M	0°	10°
S	2.50	3.00

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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